# **Dual Transistor -Power Management**

## **NPN/PNP Dual (Complimentary)**

### **Features**

- Low  $V_{CE(SAT)}$ , < 0.5 V
- These are Pb-Free Devices

### **MAXIMUM RATINGS** Q1

Rating	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc
Collector-Emitter Voltage	V <sub>CEO</sub>	50	Vdc
Collector Current	I <sub>C</sub>	100	mAdc

#### Q2

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V <sub>CEO</sub>	-60	V
Collector - Base Voltage	V <sub>CBO</sub>	-50	V
Emitter – Base Voltage	V <sub>EBO</sub>	-6.0	V
Collector Current – Continuous	I <sub>C</sub>	-100	mAdc

### THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	PD	357 (Note 1) 2.9 (Note 1)	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	350 (Note 1)	°C/W
Characteristic (Both Junctions Heated)	Symbol	Max	Unit
	,	-	J 0
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	P <sub>D</sub>	500 (Note1) 4.0 (Note 1)	mW mW/°C
	,	(Note1) 4.0	mW

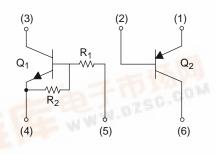
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. FR-4 @ Minimum Pad.



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SOT-563 CASE 463A PLASTIC

### **MARKING DIAGRAM**



UV = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
EMF18XV6T5	SOT-563 (Pb-Free)	8000/Tape & Reel
EMF18XV6T5G	SOT-563 (Pb-Free)	8000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications



### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ ) (Note 2)

Characteristic	Symbol	Min	Тур	Max	Unit	
Q1: NPN						
Collector-Base Cutoff Current (V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0)	I <sub>CBO</sub>	_	_	100	nAdc	
Collector-Emitter Cutoff Current (V <sub>CE</sub> = 50 V, I <sub>B</sub> = 0)	I <sub>CEO</sub>	-	_	500	nAdc	
Emitter-Base Cutoff Current (V <sub>EB</sub> = 6.0 V, I <sub>C</sub> = 0)	I <sub>EBO</sub>	-	_	0.1	mAdc	
Collector-Base Breakdown Voltage ( $I_C = 10 \mu A, I_E = 0$ )	V <sub>(BR)CBO</sub>	50	-	-	Vdc	
Collector-Emitter Breakdown Voltage (Note 4) (I <sub>C</sub> = 2.0 mA, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	50	-	-	Vdc	
DC Current Gain (V <sub>CE</sub> = 10 V, I <sub>C</sub> = 5.0 mA)	h <sub>FE</sub>	80	140	-		
Collector-Emitter Saturation Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.3 mA)	V <sub>CE(sat)</sub>	-	-	0.25	Vdc	
Output Voltage (on) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 3.5 V, R <sub>L</sub> = 1.0 k $\Omega$ )	V <sub>OL</sub>	-	-	0.2	Vdc	
Output Voltage (off) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 0.5 V, R <sub>L</sub> = 1.0 k $\Omega$ )	V <sub>OH</sub>	4.9	-	-	Vdc	
Input Resistor	R1	32.9	47	61.1	kΩ	
Resistor Ratio	R1/R2	0.8	1.0	1.2		
Q2: PNP						
Collector–Base Breakdown Voltage ( $I_C = -50 \mu Adc, I_E = 0$ )	V <sub>(BR)CBO</sub>	-60	-	-	Vdc	
Collector–Emitter Breakdown Voltage ( $I_C = -1.0 \text{ mAdc}, I_B = 0$ )	V <sub>(BR)CEO</sub>	-50	-	-	Vdc	
Emitter-Base Breakdown Voltage ( $I_E = -50 \mu Adc$ , $I_E = 0$ )	V <sub>(BR)EBO</sub>	-6.0	-	-	Vdc	
Collector–Base Cutoff Current (V <sub>CB</sub> = -30 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	-	-0.5	nA	
Emitter-Base Cutoff Current (V <sub>EB</sub> = -5.0 Vdc, I <sub>B</sub> = 0)	I <sub>EBO</sub>	-	-	-0.5	μΑ	
Collector–Emitter Saturation Voltage (Note 4) $(I_C = -50 \text{ mAdc}, I_B = -5.0 \text{ mAdc})$	V <sub>CE(sat)</sub>	-	-	-0.5	Vdc	
DC Current Gain (Note 4) (V <sub>CE</sub> = -6.0 Vdc, I <sub>C</sub> = -1.0 mAdc)	h <sub>FE</sub>	120	-	560	_	
Transition Frequency ( $V_{CE} = -12 \text{ Vdc}$ , $I_{C} = -2.0 \text{ mAdc}$ , $f = 30 \text{ MHz}$ )	f <sub>T</sub>	-	140	-	MHz	
Output Capacitance (V <sub>CB</sub> = -12 Vdc, I <sub>E</sub> = 0 Adc, f = 1.0 MHz)	C <sub>OB</sub>	-	3.5	-	pF	

Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.
 Pulse Test: Pulse Width ≤ 300 µs, D.C. ≤ 2%.

### TYPICAL ELECTRICAL CHARACTERISTICS — Q1, NPN

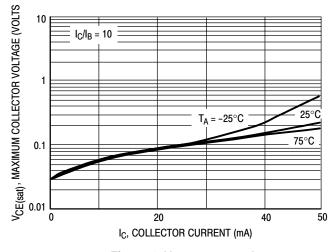


Figure 1.  $V_{CE(sat)}$  versus  $I_{C}$ 

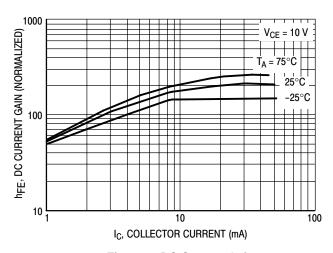


Figure 2. DC Current Gain

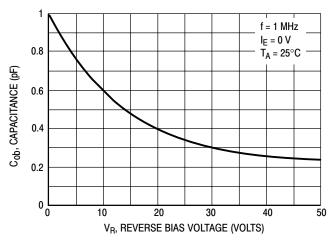


Figure 3. Output Capacitance

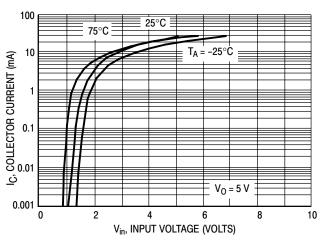


Figure 4. Output Current versus Input Voltage

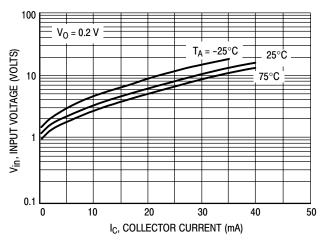


Figure 5. Input Voltage versus Output Current

### TYPICAL ELECTRICAL CHARACTERISTICS - Q2, PNP

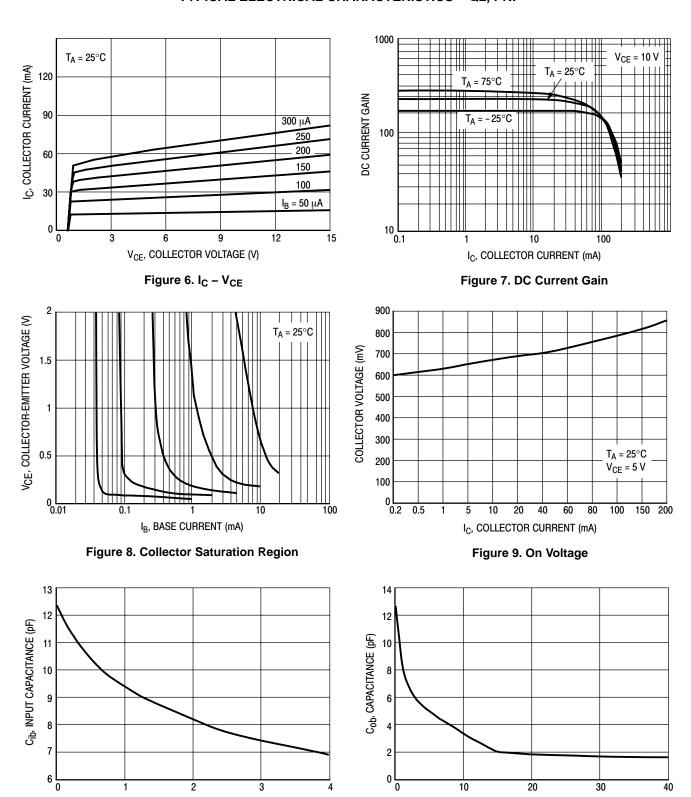


Figure 11. Capacitance

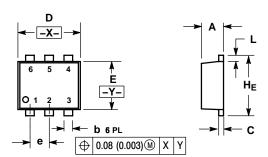
V<sub>CB</sub> (V)

 $V_{EB}(V)$ 

Figure 10. Capacitance

#### PACKAGE DIMENSIONS

SOT-563, 6 LEAD CASE 463A-01 ISSUE F

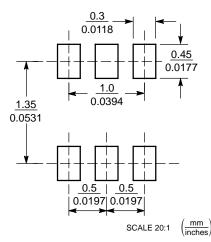


#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
   Y14 5M 1982
- Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.021	0.023
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.12	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.062	0.066
Е	1.10	1.20	1.30	0.043	0.047	0.051
е	0.5 BSC			(	0.02 BS0	
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.50	1.60	1.70	0.059	0.062	0.066

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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